MA3J1470G

Silicon epitaxial planar type

For high-speed switching circuits

■ Features

- Two isolated elements contained in one package, allowing highdensity mounting
- Two diodes are connected in series in the package

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter		Symbol	Rating	Unit
Reverse voltage		V_R	80	V
Maximum peak reverse voltage		V_{RM}	80	V
Forward current	Single	I_{F}	100	mA
	Series		65	
Peak forward	Single	I_{FM}	225	mA
current	Series		145	
Non-repetitive peak	Single	I_{FSM}	500	mA
forward surge current *	Series		325	
Junction temperature		T _j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C

Note) *: t = 1 s

Package

- Code
 - SMini3-F2
- Pin Name
 - 1: Anode1
 - 2: Cathode2
 - 3: Cathode1, Anode2
- Marking Symbol: MS
- Internal Connection

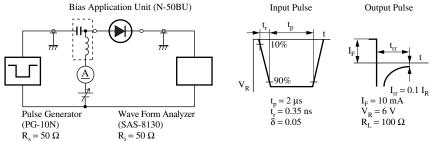


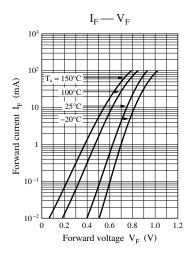
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

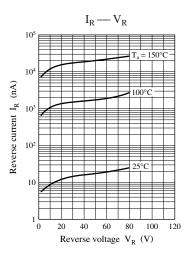
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{\rm F}$	$I_F = 100 \text{ mA}$			1.2	V
Reverse voltage	V_R	$I_R = 100 \mu A$	80			V
Reverse current	I_R	$V_R = 75 \text{ V}$			100	nA
Terminal capacitance	C _t	$V_R = 0 V, f = 1 MHz$			2	pF
Reverse recovery time *	t _{rr}	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}$			3	ns
		$I_{rr} = 0.1 I_R, R_L = 100 \Omega$				

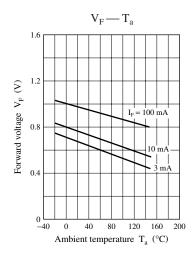
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

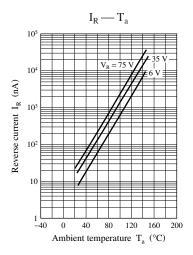
- 2. Absolute frequency of input and output is 100 MHz.
- 3. *: t_{rr} measurement circuit

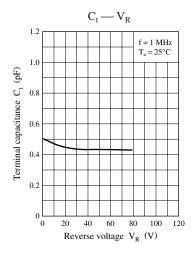


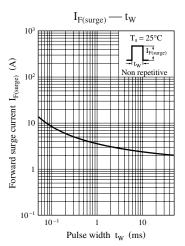






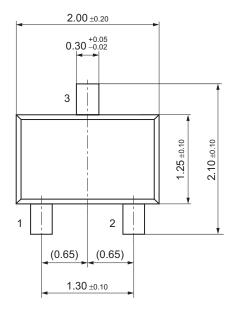


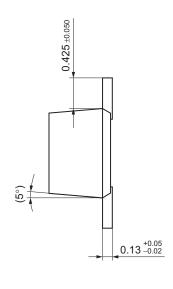


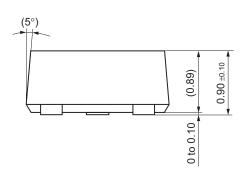


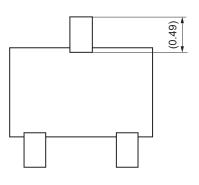
2 SKF00096AED

SMini3-F2 Unit: mm









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